

### **NCE N-Channel Super Trench II Power MOSFET**

### **Description**

The NCEP068N10AG uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

### **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

### **General Features**

- V<sub>DS</sub> =100V,I<sub>D</sub> =85A
  - $R_{DS(ON)}$ =6.1m $\Omega$  (typical) @  $V_{GS}$ =10V  $R_{DS(ON)}$ =8.3m $\Omega$  (typical) @  $V_{GS}$ =4.5V
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 150 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!

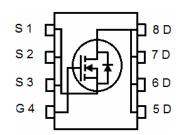
#### **DFN 5X6**





**Top View** 

**Bottom View** 



**Schematic Diagram** 

### **Package Marking and Ordering Information**

	Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
Ī	P068N10AG	NCEP068N10AG	DFN5X6-8L	-	-	-

Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Para	neter	Symbol	Limit	Unit
Drain-Source Voltage		V <sub>DS</sub>	100	V
Gate-Source Voltage		V <sub>G</sub> s	±20	V
Drain Current-Continuous		I <sub>D</sub>	85	Α
Drain Current-Continuous(T <sub>C</sub> =100	)°C)	I <sub>D</sub> (100℃)	61	Α
Pulsed Drain Current		I <sub>DM</sub>	340	Α
Maximum Power Dissipation		P <sub>D</sub>		W
Derating factor		0.84		W/℃
Single pulse avalanche energy (Note 5)		E <sub>AS</sub>	320	mJ
V <sub>DS</sub> Spike <sup>(Note 6)</sup>	10µs	120		V
Operating Junction and Storage T	emperature Range	$T_{J}, T_{STG}$	T <sub>J</sub> ,T <sub>STG</sub> -55 To 150	

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case (Note 2)	R <sub>θJC</sub>	1.2	°C/W
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# NCEP068N10AG

### Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

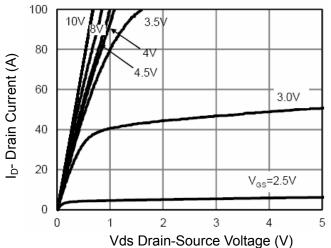
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	100		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.2	1.8	2.4	V
Drain-Source On-State Resistance	В	V <sub>GS</sub> =10V, I <sub>D</sub> =40A	-	6.1	6.8	mΩ
Dialii-Source Oil-State Resistance	R <sub>DS(ON)</sub>	$V_{GS}$ =10V, $I_{D}$ =40A $V_{GS}$ =4.5V, $I_{D}$ =40A $V_{DS}$ =5V, $I_{D}$ =20A $V_{DS}$ =50V, $V_{GS}$ =0V,	-	8.3	9.8	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A		60	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\/ -50\/\/ -0\/	-	4680	-	PF
Output Capacitance	Coss		-	316	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	14.5	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	$t_{d(on)}$		-	10	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD} = 50V, I_{D} = 40A$	-	6	-	nS
Turn-Off Delay Time	$t_{d(off)}$	$V_{GS}$ =10 $V$ , $R_{G}$ =3 $\Omega$	-	51	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	9	-	nS
Total Gate Charge	$Q_g$	\/ -50\/   -40	-	76	-	nC
Gate-Source Charge	$Q_{gs}$	$V_{DS}$ =50V, $I_D$ =40A,	-	15.3		nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	17.3		nC
Drain-Source Diode Characteristics			•		-	
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =40A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	85	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C, I_F = 40A$	-	55	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	135	-	nC

### Notes:

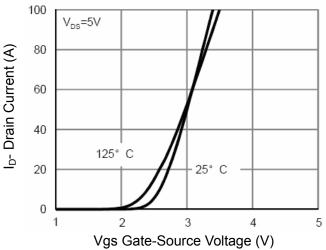
- ${\it 1. Repetitive Rating: Pulse width \ limited \ by \ maximum \ junction \ temperature.}$
- 2. Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\text{C}$  ,V  $_{\text{DD}}$  =50 V,V  $_{\text{G}}$  =10 V,L=0.5 mH,Rg=25  $\Omega$
- 6. The spike duty cycle 5% max, limited by junction temperature  $T_{J}(\mbox{MAX})\mbox{=}125\,^{\circ}\,$  C



### **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

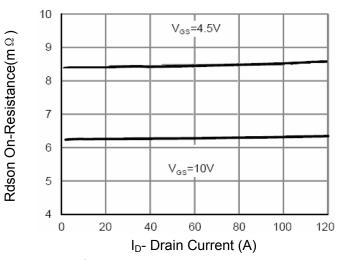
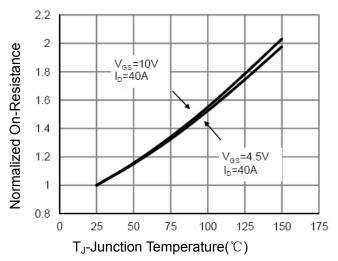


Figure 3 Rdson- Drain Current



**Figure 4 Rdson-Junction Temperature** 

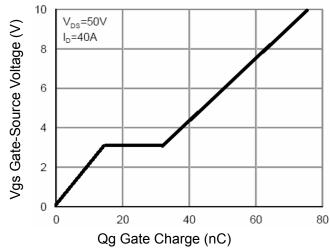


Figure 5 Gate Charge

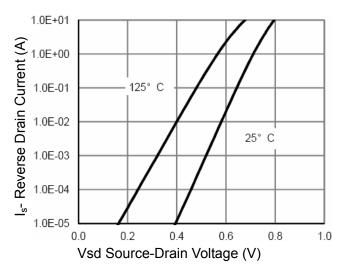


Figure 6 Source- Drain Diode Forward

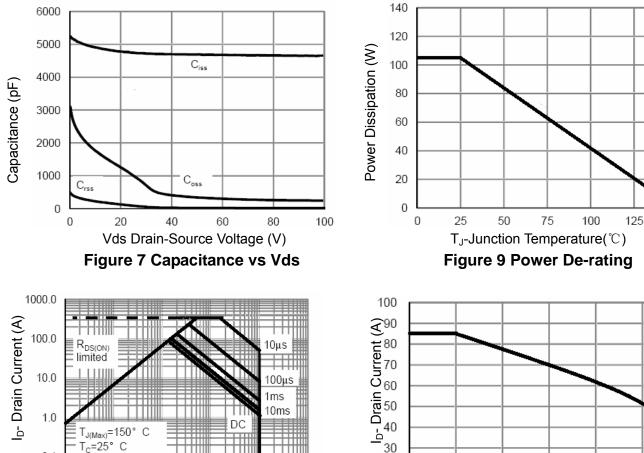
150



0.1

0.01

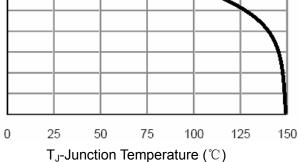
0.1



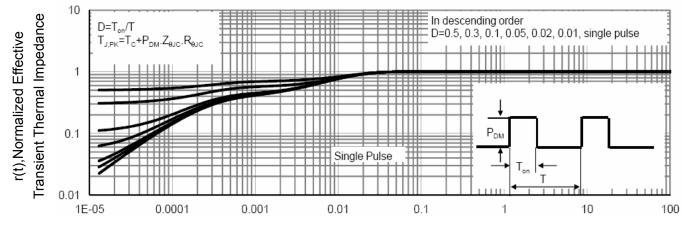
1000

Vds Drain-Source Voltage (V)
Figure 8 Safe Operation Area

10



### **Figure 10 Current De-rating**



Square Wave Pluse Duration(sec)

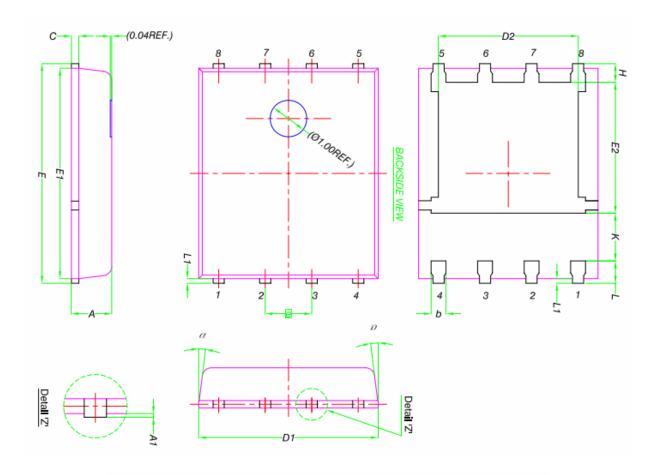
Figure 11 Normalized Maximum Transient Thermal Impedance

20 10

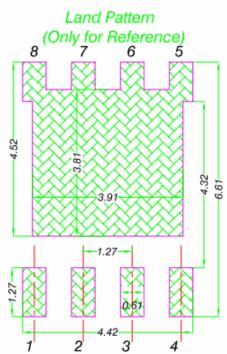
0



### **DFN5X6-8L Package Information**



	MILLIMETERS			
DIM.	MIN.	NOM.	MAX.	
Α	0.90	1.00	1.10	
A1	0	-	0.05	
b	0.33	0.41	0.51	
С	0.20	0.25	0.30	
D1	4.80	4.90	5.00	
D2	3.61	3.81	3.96	
Ε	5.90	6.00	6.10	
E1	5.70	5.75	5.80	
E2	3.38	3.58	3.78	
е	1.27 BSC			
Н	0.41 0.51		0.61	
К	1.10	-	-	
L	0.51	0.61	0.71	
L1	0.06	0.13	0.20	
α	0°	-	12°	





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## NCEP068N10AG

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